SLRS022A - DECEMBER 1976 - REVISED OCTOBER 1995

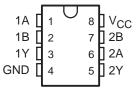
PERIPHERAL DRIVERS FOR HIGH-VOLTAGE, HIGH-CURRENT DRIVER APPLICATIONS

- Characterized for Use to 300 mA
- High-Voltage Outputs
- No Output Latch-Up at 30 V (After Conducting 300 mA)
- Medium-Speed Switching
- Circuit Flexibility for Varied Applications and Choice of Logic Function
- TTL-Compatible Diode-Clamped Inputs
- Standard Supply Voltages
- Plastic DIP (P) With Copper Lead Frame for Cooler Operation and Improved Reliability
- Package Options Include Plastic Small Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

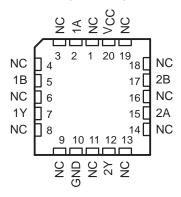
SUMMARY OF SERIES 55461/75461

DEVICE	LOGIC	PACKAGES
SN55461	AND	FK, JG
SN55462	NAND	FK, JG
SN55463	OR	FK, JG
SN75461	AND	D, P
SN75462	NAND	D, P
SN75463	OR	D, P

SN55461, SN55462, SN55463 . . . JG PACKAGE SN75461, SN75462, SN75463 . . . D OR P PACKAGE (TOP VIEW)



SN55461, SN55462, SN55463 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

description

These dual peripheral drivers are functionally interchangeable with SN55451B through SN55453B and SN75451B through SN75453B peripheral drivers, but are designed for use in systems that require higher breakdown voltages than those devices can provide at the expense of slightly slower switching speeds. Typical applications include logic buffers, power drivers, relay drivers, lamp drivers, MOS drivers, line drivers, and memory drivers.

The SN55461/SN75461, SN55462/SN75462, and SN55463/SN75463 are dual peripheral AND, NAND, and OR drivers respectively (assuming positive logic), with the output of the gates internally connected to the bases of the npn output transistors.

Series SN55461 drivers are characterized for operation over the full military temperature range of -55°C to 125°C. Series SN75461 drivers are characterized for operation from 0°C to 70°C.

SN55461 THRU SN55463 SN75461 THRU SN75463 DUAL PERIPHERAL DRIVERS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

		SN55'	SN75'	UNIT		
Supply voltage, V _{CC} (see Note 1)		7	7	V		
Input voltage, V _I		5.5	5.5	V		
Intermitter voltage (see Note 2)		5.5	5.5	V		
Off-state output voltage, VO	35	35	V			
Continuous collector or output current (see Note 3)	400	400	mA			
Peak collector or output current ($t_W \le 10$ ms, duty cycle $\le 50\%$, see No.	ote 4)	500	500	mA		
Continuous total power dissipation		See Diss	See Dissipation Rating Table			
Operating free-air temperature range, TA		-55 to 125	0 to 70	°C		
Storage temperature range, T _{Stg}		-65 to 150	-65 to 150	°C		
Case temperature for 60 seconds, T _C	FK package	260		°C		
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG package	300		°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or P package		260	°C		

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. Voltage values are with respect to network GND unless otherwise specified.

- 2. This is the voltage between two emitters A and B.
- 3. This value applies when the base-emitter resistance (RBE) is equal to or less than 500 Ω .
- 4. Both halves of these dual circuits may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous dissipation rating.

DISSIPATION RATING TABLE

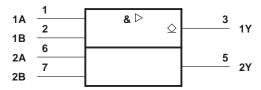
PACKAGE	T _A ≤ 25°C POWER RATING	**		T _A = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	-
FK	1375 mW	11.0 mW/°C	880 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
Р	1000 mW	8.0 mW/°C	640 mW	-

recommended operating conditions

	SN55'			SN75'			LINUT
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	4.5	5	5.5	4.75	5	5.25	V
High-level input voltage, V _{IH}	2			2			V
Low-level input voltage, V _{IL}			0.8			0.8	V
Operating free-air temperature, TA	-55		125	0		70	°C



logic symbol†



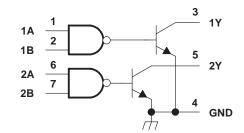
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for D, JG, and P packages.

FUNCTION TABLE (each driver)

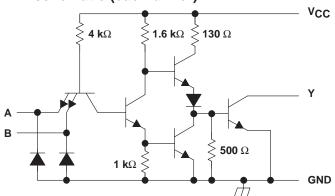
Α	В	Υ
L	L	L (on state)
L	Н	L (on state)
Н	L	L (on state)
Н	Н	H (off state)

positive logic: $\underline{\underline{}}$ Y = AB or \overline{A} + \overline{B}

logic diagram (positive logic)



schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

	DADAMETED			5	SN55461		SN75461			
	PARAMETER	TEST CONDITIONS†		MIN	TYP [‡]	MAX	MIN	TYP [‡]	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	$I_{I} = -12 \text{ mA}$		-1.2	-1.5		-1.2	-1.5	V
ГОН	High-level output current	V _{CC} = MIN, V _{OH} = 35 V	V _{IH} = MIN,			300			100	μΑ
V	Low-level output voltage	V _{CC} = MIN, I _{OL} = 100 mA			0.25	0.5		0.25	0.4	
VOL		V _{CC} = MIN, I _{OL} = 300 mA			0.5	0.8		0.5	0.7	V
Ц	Input current at maximum input voltage	$V_{CC} = MAX$,	V _I = 5.5 V			1			1	mA
lн	High-level input current	$V_{CC} = MAX$,	V _I = 2.4 V			40			40	μΑ
I _I L	Low-level input current	$V_{CC} = MAX$,	V _I = 0.4 V		-1	-1.6		-1	-1.6	mA
ICCH	Supply current, outputs high	$V_{CC} = MAX$,	V _I = 5 V		8	11		8	11	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX$,	V _I = 0		56	76		56	76	mA

For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

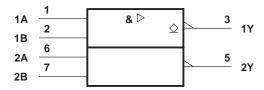
switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER			TEST CONDITIONS			MAX	UNIT
^t PLH	Propagation delay time, low-to-high-level o	utput				30	55	
tPHL	Propagation delay time, high-to-low-level output		I _O ≈ 200 mA,	$C_L = 15 pF$,		25	40	
tTLH	Transition time, low-to-high-level output			See Figure 1		8	20	ns
tTHL	Transition time, high-to-low-level output	el output				10	20	
V	V Dish level extent college a street existing		V _S = 30 V,	I _O ≈ 300 mA,		V _S -10		mV
VOH	High-level output voltage after switching	SN75461	See Figure 2	-	V _S -10			IIIV



[‡] All typical values are at V_{CC} = 5 V, T_A = 25°C.

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

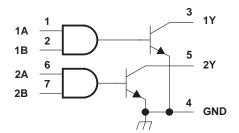
Pin numbers shown are for D, JG, and P packages.

FUNCTION TABLE (each driver)

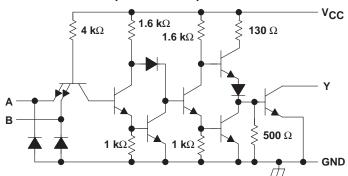
Α	В	Y
L	L	H (off state)
L	Н	H (off state)
Н	L	H (off state)
Н	Н	L (on state)

positive logic: $\underline{}$ Y = AB or A + B

logic diagram (positive logic)



schematic (each driver)



Resistor values shown are nominal.

electrical characteristics over recommended operating free-air temperature range

	24244555		.p.r.evet	SN55462			SN75462			
	PARAMETER	TEST CONDITIONS†		MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT
V_{IK}	Input clamp voltage	$V_{CC} = MIN,$	$I_{I} = -12 \text{ mA}$		-1.2	-1.5		-1.2	-1.5	V
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 35 V	V _{IL} = 0.8 V,			300			100	μΑ
.,	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$			0.25	0.5		0.25	0.4	.,
VOL		V _{CC} = MIN, I _{OL} = 300 mA			0.5	0.8		0.5	0.7	V
l _l	Input current at maximum input voltage	$V_{CC} = MAX$,	V _I = 5.5 V			1			1	mA
lіН	High-level input current	$V_{CC} = MAX$,	V _I = 2.4 V			40			40	μΑ
I _{IL}	Low-level input current	$V_{CC} = MAX$,	V _I = 0.4 V		-1.1	-1.6		-1.1	-1.6	mA
ІССН	Supply current, outputs high	$V_{CC} = MAX$,	V _I = 0		13	17		13	17	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX$,	V _I = 5 V		61	76		61	76	mA

For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER			TEST CONDITIONS			MAX	UNIT
tPLH	Propagation delay time, low-to-high-level o	utput				45	65	
tPHL	PHL Propagation delay time, high-to-low-level output		$I_O \approx 200 \text{ mA},$ $R_L = 50 \Omega,$	$C_L = 15 pF$,		30	50	
tTLH	TLH Transition time, low-to-high-level output			See Figure 1		13	25	ns
tTHL	t _{THL} Transition time, high-to-low-level output		7			10	20	
V	High-level output voltage after switching	SN55462	$V_S = 30 \text{ V},$	I _O ≈ 300 mA,		V _S -10		mV
VOH	riigii-ievei output voitage aiter switching	SN75462	See Figure 2		V _S -10			IIIV



[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

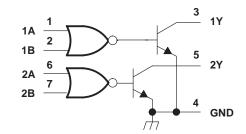
Pin numbers shown are for D, JG, and P packages.

FUNCTION TABLE (each driver)

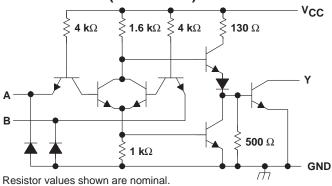
Α	В	Υ
L	L	L (on state)
L	Н	H (off state)
Н	L	H (off state)
Н	Н	H (off state)

positive logic: $Y = A + B \text{ or } \overline{\overline{A} \overline{B}}$

logic diagram (positive logic)



schematic (each driver)



electrical characteristics over recommended operating free-air temperature range

	DADAMETED	TEOT 001	IDITIONOT	SN55463			SN75463			LINUT
	PARAMETER	TEST CONDITIONS†		MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT
٧IK	Input clamp voltage	$V_{CC} = MIN,$	$I_I = -12 \text{ mA}$		-1.2	-1.5		-1.2	-1.5	V
ЮН	High-level output current	V _{CC} = MIN, V _{OH} = 35 V	V _{IH} = MIN,			300			100	μΑ
V	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$			0.25	0.5		0.25	0.4	V
VOL		$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$	V _{IL} = 0.8 V,		0.5	0.8		0.5	0.7	V
Ц	Input current at maximum input voltage	$V_{CC} = MAX$,	V _I = 5.5 V			1			1	mA
ΊΗ	High-level input current	$V_{CC} = MAX$,	V _I = 2.4 V			40			40	μΑ
IլL	Low-level input current	$V_{CC} = MAX$,	V _I = 0.4 V		-1	-1.6		-1	-1.6	mA
ICCH	Supply current, outputs high	$V_{CC} = MAX$,	V _I = 5 V		8	11		8	11	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX$,	V _I = 0		58	76		58	76	mA

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

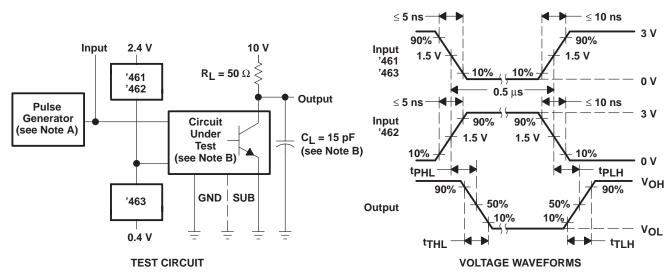
switching characteristics, $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CO	TEST CONDITIONS			MAX	UNIT	
tPLH	LH Propagation delay time, low-to-high-level output					30	55	
tPHL	Propagation delay time, high-to-low-level output			C _L = 15 pF, See Figure 1		25	40	
tTLH	-LH Transition time, low-to-high-level output					8	25	ns
tTHL	Transition time, high-to-low-level output				10	25		
V	High level extent valte as after existable a	SN55463	V _S = 30 V,	l _O ≈ 300 mA,		V _S -10		mV
VOH	High-level output voltage after switching	SN75463	See Figure 2	-	V _S -10			IIIV



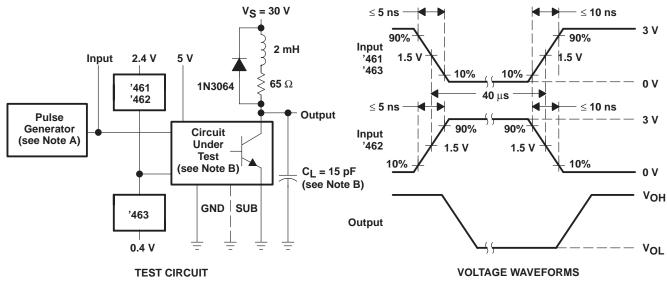
[‡] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The pulse generator has the following characteristics: PRR \leq 1 MHz, $Z_O\approx50~\Omega$
 - B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms for Switching Times



- NOTES: A. The pulse generator has the following characteristics: PRR \leq 12.5 kHz, Z_O = 50 Ω .
 - B. C_L includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms for Latch-Up Test





PACKAGE OPTION ADDENDUM

www.ti.com 15-Oct-2009

PACKAGING INFORMATION

Orderable	e Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
JM38510/1	2908BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
JM38510/1	2909BPA	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
SN554	61JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
SN554	62JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
SN554	63JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
SN754	461D	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
SN754	461P	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
SN754	462D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN7546	62DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN7546	S2DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN754	62DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75462	2DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN75462	2DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN754	462P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN7546	62PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN754	463D	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
SN754	63DR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
SN754	463P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SN7546	63PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
SNJ554	161FK	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
SNJ554	161JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
SNJ554	162FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
SNJ554	162JG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type
SNJ554	163JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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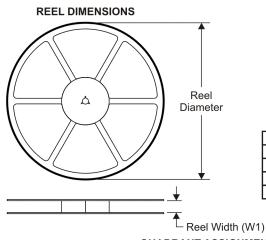
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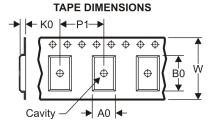




.com 19-Mar-2008

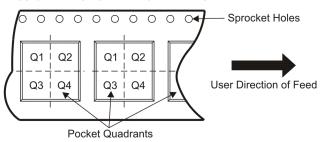
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	_	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75462DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

19-Mar-2008

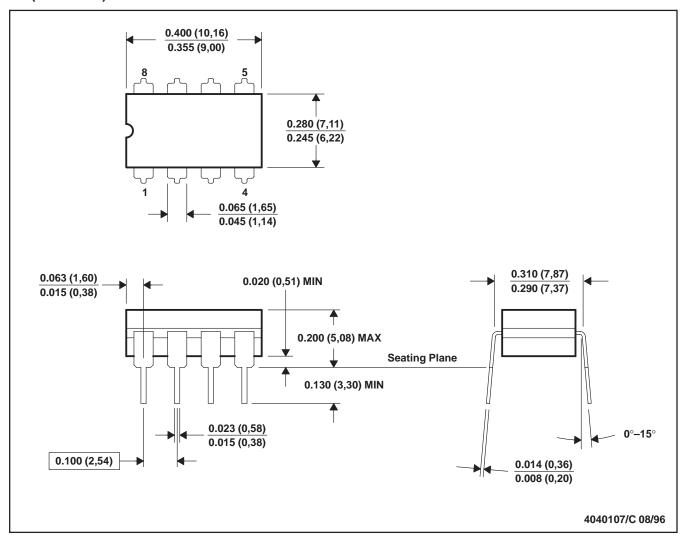


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75462DR	SOIC	D	8	2500	340.5	338.1	20.6

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



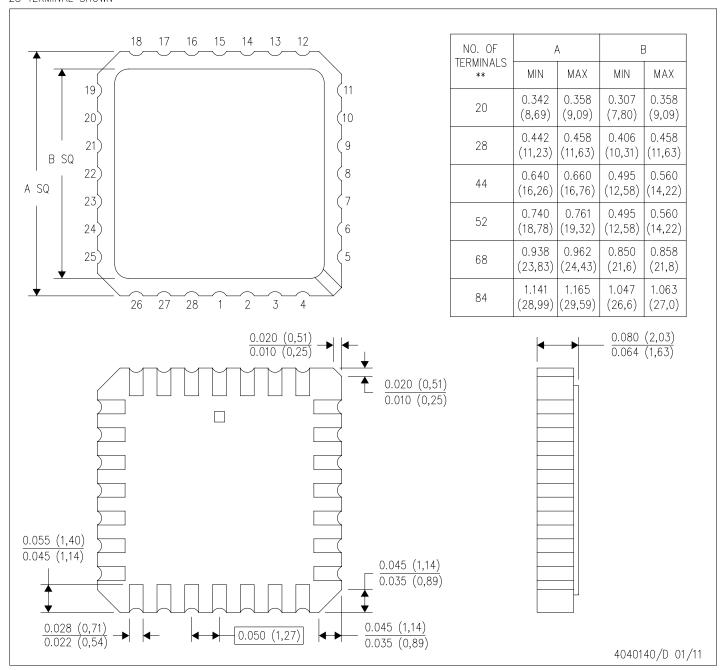
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN

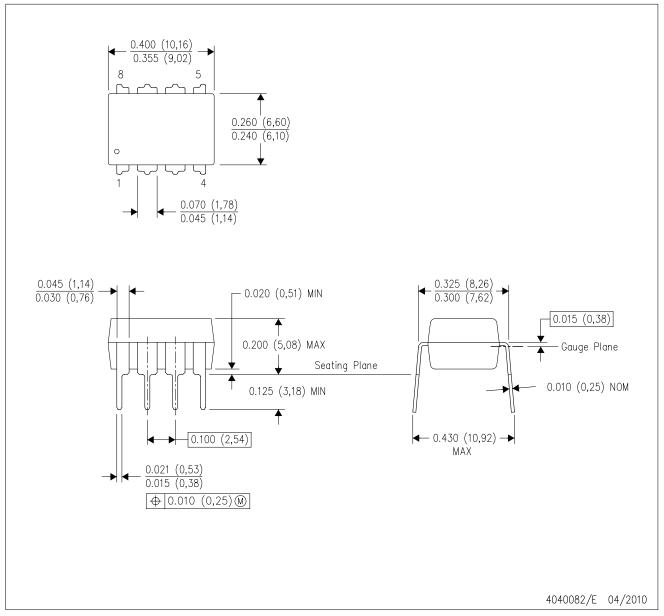


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE

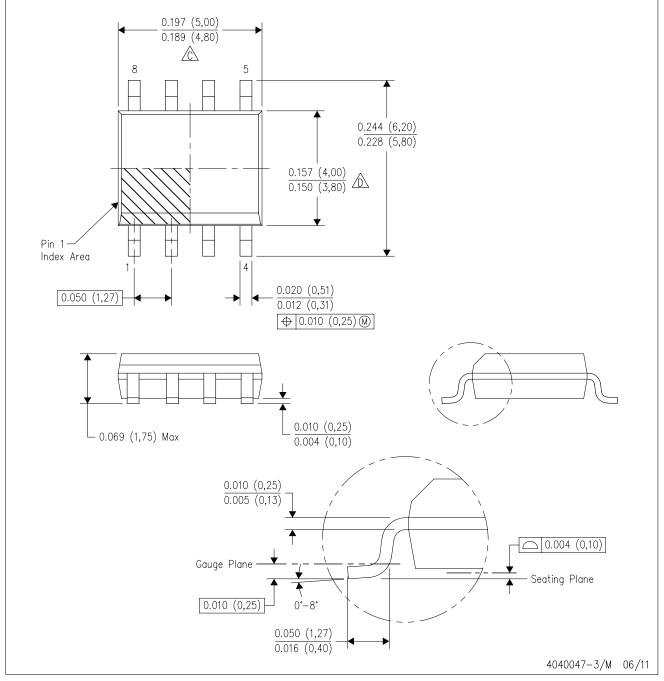


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



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